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J.S. <b>UTILITY</b> Patent Application				
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ISSUING CLASSIFICATION  CROSS REFERENCE(S)					
CLASS SÜBCLASS		CLASS SUBCLASS (ONE SUBCLASS PER BLOCK)			
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TERMINAL DISCLAIMER	DRAWINGS			<b>CLAIMS ALLOWED</b>	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
☐ The term of this patent		1		NOTICE OF ALLOWANCE MAILED	
subsequent to (date) has been disclaimed.	(Assistant	Examiner)	(Date)		
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